

LSC08065Q8

SILICON CARBIDE SCHOTTKY DIODE

REVERSE VOLTAGE - 650 Volts **FORWARD CURRENT** - 8 Amperes

FEATURES

- · Positive temperature coefficient for safe operation and easy of paralleling
- 175°C maximum operating junction temperature
- Extremely fast switching not dependent on temperature
- · Essentially no reverse or forward recovery

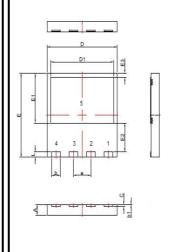
APPLICATION

- Power converters
- Switching-mode power supplies
- Power Factor correction modules

MECHANICAL DATA

- · Case: DFN8080 molded plastic
- · Case Material: "Green" molding compound, UL flammability classification 94V-0,(No Br. Sb. Cl.) "Halogen-free".
- Moisture Sensitivity Level 3 per J-STD-020
- · Lead free finish, RoHS compliant
- Weight: 0.214 grams (Approximate)
- Marking code: LSC08065Q8

DFN8080



DFN8080					
DIM	MIN	MAX			
Α	0.90	1.10			
b	0.90	1.10			
b1	0.00	0.05			
С	0.20	REF			
D	7.90	8.10			
D1	7.10	7.30			
E	7.90	8.10			
E1	4.65	4.85			
E2	2.65	2.85			
E3	0.30	0.50			
е	2.0 BSC				
L	0.40	0.60			
All d mension in millimeter					

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATINGS

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	650	V
Maximum DC blocking voltage		V _{DC}	650	V
Maximum Average rectified output current @Tc=100°C		I _(AV)	8	Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load.		I _{FSM}	38	Α
Operating junction and Storage Temperature range		T _J , T _{STG}	-55 ~ +175	°C

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST C	TEST CONDITIONS		TYP	MAX	UNIT
Forward voltage (Note1)	I _F =8A	T _J =25°C T _J =175°C	V _F	 2.04	1.70 2.25	V
Reverse Leakage current	V _R =650V	T _J =25°C T _J =175°C	I _R	 6.2	230 550	uA
Typical junction capacitance (Note 2)		CJ	270		pF	

DYNAMIC ELECTRICAL CHARACTERISTICS

PARAMCETER	TEST CONDITIONS	SYMBOL	TYP	UNIT
Total capacitive charge	V _R =400V,dI/dt=250A/us, I _F =8A	Qc	19	nC

THERMAL CHARACTERISTICS

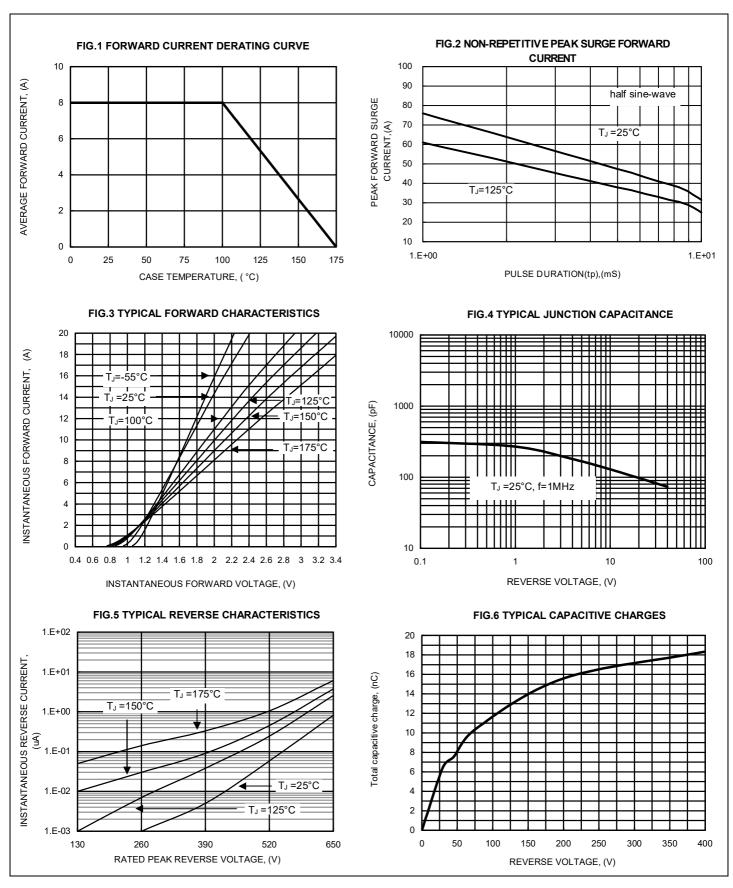
PARAMETER	SYMBOL	TYP		UNIT	
Typical thermal registance (Neto 2.4)	RthJc	4		°C/W	
Typical thermal resistance (Note 3,4)	RthJ∟	5		C/VV	
Note:	REV7, Jan-2019, k	KTGR01			

Note: (1) 300us pulse width, 2% duty cycle.

- Measured at 1.0MHz and applied voltage of 1.0V DC.
- Thermal resistance test performed in accordance with JESD-51.
- (4) The unit mounted on copper heatsink (75mm x 75mm x 2.0mm) & copper heatsink (50mm x 50mm x 1.6mm)

RATING AND CHARACTERISTIC CURVES LSC08065Q8

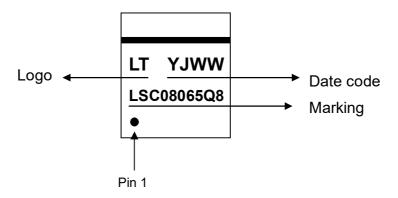




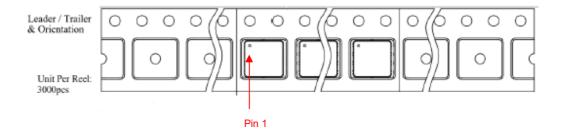
MECHANICAL AND MARKING INFORMATION LSC08065Q8



Marking Information:



Packaging Information:



DEVICE	Q'TY/REEL (PCS)	REEL DIA. (mm)	Q'TY/BOX (PCS)	Q'TY/CARTON (PCS)	BOX SIZE (mm)	CARTON SIZE (mm)
LSC08065Q8	2.5K	330	2.5K	25K	345x355x30	355x346x376



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